



# MA1078-2

For DCS1800 - 20W Power Amplifier

MA1078-2

## DESCRIPTION

The MA1078-2 is a 20W power amplifier designed for DCS 1800, which comprises 4 stages GaAs FET and 2 stages Si bipolar transistors, also RF power monitoring circuit.

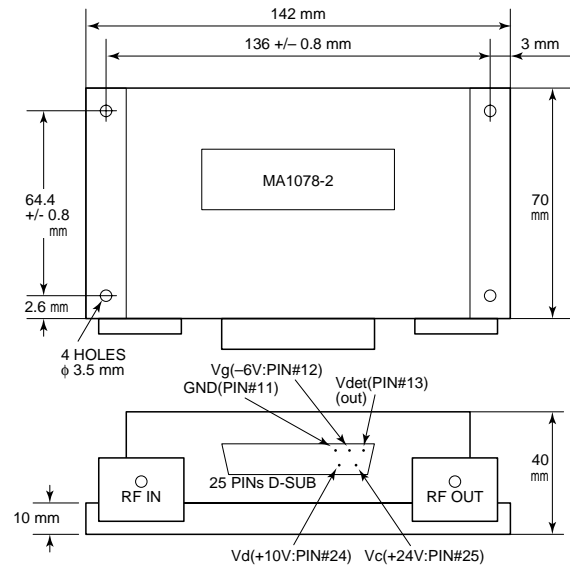
## FEATURES

- Specified +25/+10 Volt Characteristics
  - RF Output Power : +43 dBm (typ.)
  - Harmonics : -65 dBc typ.
- Small Size : 70 × 142 × 40 mm<sup>3</sup>
- 50 Ohm Input/Output Impedances

## APPLICATION

- DCS 1800 (1805 ~ 1880 MHz)  
Base station

## OUTLINE DRAWING



## 2. Electrical Performances (Tc = +25°C, Vc = +24V, Vd = +10V, Vg = -6V, Zg = Zl = 50Ω)

No.	Items	Symbol	Condition	Standard			Unit
				Min	Type	Max	
1	Frequency	f		1805	---	1880	MHz
2	Output Power	P <sub>out</sub>		+43	---	---	dBm
3	Output RF modulation spectrum ; from the carrier	----	P <sub>out</sub> = +43 dBm (P <sub>in</sub> control)	----	----		
	100 KHz			----	----	+0.5	dB
	200 KHz			----	----	-30	dB
	250 KHz			----	----	-33	dB
	400 KHz			----	----	-60	dB
	600 KHz			----	----	-70	dB
	to < 1200 KHz						
	1200 KHz			----	----	-73	dB
	to < 1800 KHz						
	1800 KHz			----	----	-75	dB
	to < 6000 KHz						
	≤ 6000 KHz			----	----	-80	dB
4	Spurious ; in-band out-band			----	----	-36 -30	dBm dBm
5	Harmonics	2fo 3fo 4fo	P <sub>out</sub> = +43 dBm	----	-60 -65 -70	----	dBc dBc dBc
6	Quiescent current	I <sub>cq</sub>	P <sub>in</sub> = 0mW	----	----	1.5	A

## Amplifier Specifications (MA1078-2)

### 1. Maximum Ratings

No.	Items	Symbol	Condition	Standard	Unit
1	Case temperature	T <sub>c</sub>		-40 ~ +70	°C
2	Storage temperature	T <sub>stg</sub>		-40 ~ +80	°C
3	Collector Voltage	V <sub>c</sub>		+26.0	V
4	Drain Voltage	V <sub>d</sub>	V <sub>g</sub> = -6V	+11.5	V
5	Gate Voltage	V <sub>g</sub>	V <sub>d</sub> = +10V	-10.0	V
6	RF Input Power	P <sub>in</sub>		-11.0	dBm